

Ultra-Fast Recovery Diodes 10A FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-252
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1060DL
Device marking code			MUR1060DL
Repetitive Peak Reverse Voltage	VRRM	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	50
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	12.5
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C _j	pF	42

MUR1060DL

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	IFM=10.0A @Tj=25°C	-	2.25	3.2
			IFM=10.0A @Tj=150°C	-	-	2.2
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	VRM=VRRM Tj=25°C	-	-	10
	I_{RRM2}		VRM=VRRM Tj=150°C	-	25	50
Reverse Recovery Time	Trr	ns	IF=0.5A IRRM=1A IRR=0.25A Tj=25°C	-	17	25
			Tj=25°C	-	60.56	-
			Tj=125°C	-	111.70	-
Peak recovery current	I_{RRM}	A	Tj=25°C	IF=10A di/dt=-200A/us VRM=200V	2.45	-
			Tj=125°C		4.35	-
Reverse recovery charge	Qrr	nC	Tj=25°C		78.58	-
			Tj=125°C		245.59	-

■Thermal Characteristics (Tj=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MUR1060DL
Thermal Resistance	Between junction and case	RθJ-C	°CW	5.0
Thermal Resistance	Between junction and Air	RθJ-A	°CW	50

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1060DL	Approximate 0.31	2500	2500	25000	Reel

■ Characteristics (Typical)

FIG1: I_o - T_c Curve

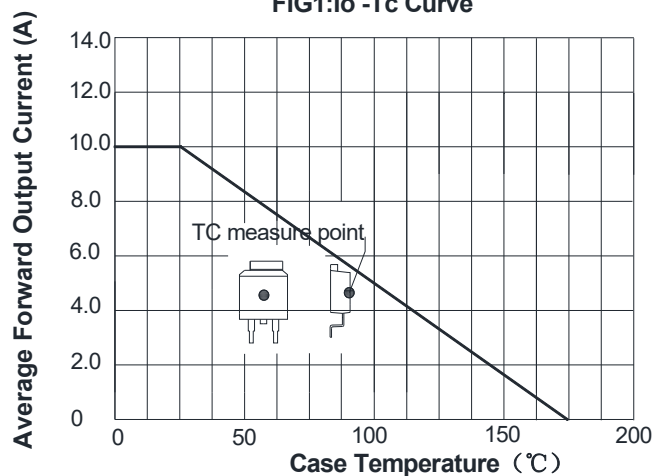


FIG2: Surge Forward Current Capability

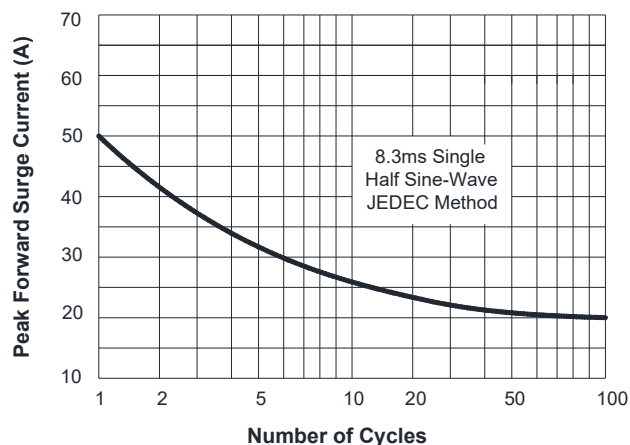


FIG3: Forward Voltage

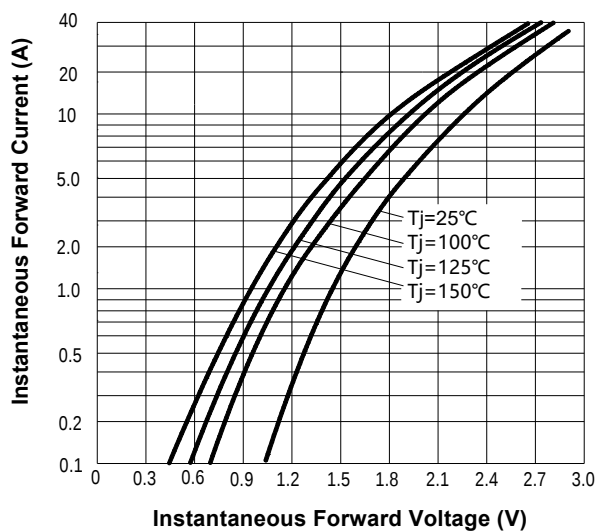


FIG.4: Instantaneous Reverse Characteristics

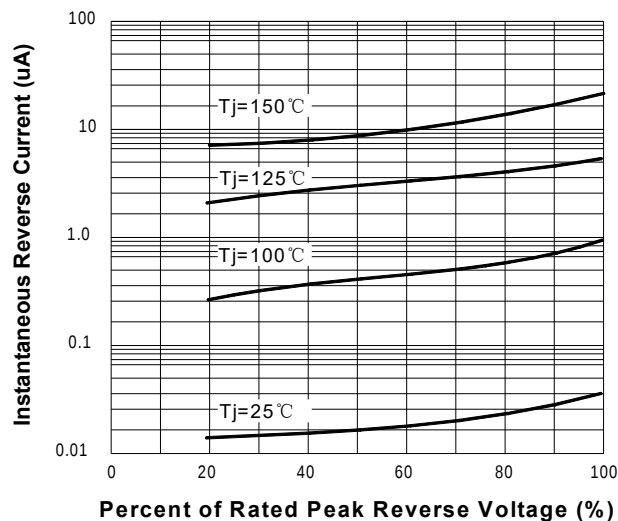
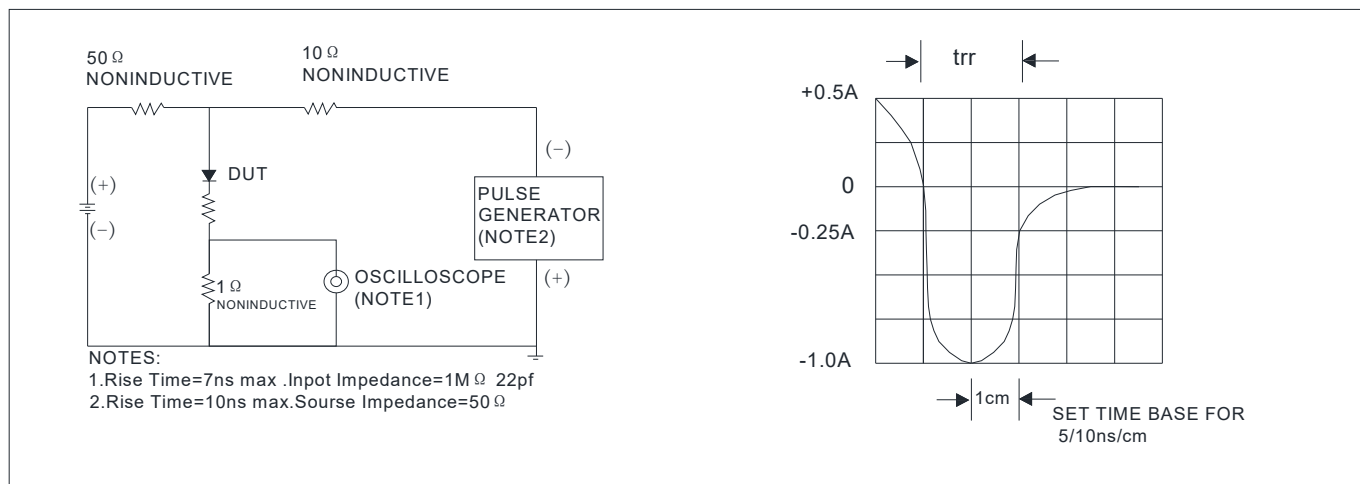
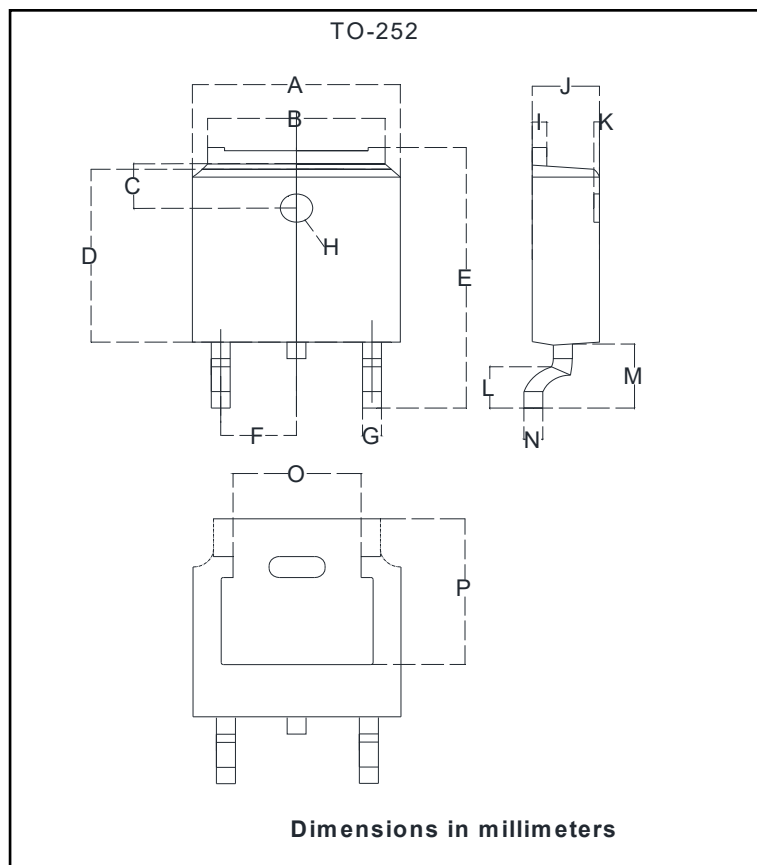


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

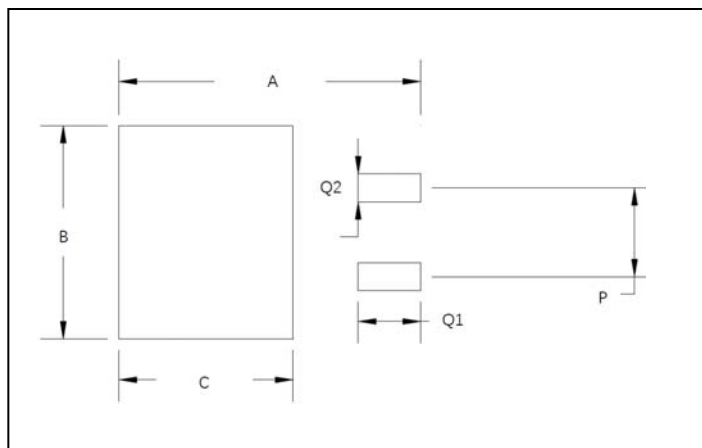


■ **Outline Dimensions**



TO-252		
Dim	Min	Max
A	6.500	6.700
B	5.100	5.460
C	1.400	1.800
D	6.000	6.200
E	10.000	10.400
F	2.166	2.366
G	0.660	0.860
H	Φ1.050	Φ1.350
I	0.460	0.580
J	2.200	2.400
K	0	0.300
L	0.890	2.290
M	2.730	3.080
N	0.430	0.580
O	4.20	4.95
P	5.15	5.45

■ **Suggested Pad Layout**



Dim	Millimeters
A	11.4
B	6.74
C	6.23
P	4.56
Q1	2.28
Q2	1.52

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